Inventors' Declaration and Power of Attorney

matt	My residence, post We (I) believe that	office address and we are (I am) the	original, first and joint	(sole) inventor(s)	ny name, of the subject					
	My residence, post office address and citizenship are as stated below next to my name, We (I) believe that we are (I am) the original, first and joint (sole) inventor(s) of the subject which is claimed and for which a patent is sought on the invention entitled: Metal Oxide Semiconductor Integrated Transistor Devices The specification of which: is attached hereto. is attached hereto including a preliminary amendment. was filed on as U.S. Application No.									
	The specification o	f which:								
	is attached hereto in was filed on was filed on including therewith	a preliminary ame	as U.S. Applicati as U.S. Applicati	on No.						
this a foreig which ident Intern	We (I) hereby state fication, including the We (I) acknowledge pplication as defined in	that we (I) have reclaims, as amende the duty to disclor Section 1.56 of I foreign priority bettent or inventor's e country other the g the box, any forwing a filing date b	viewed and understand d by any amendment re se information known litle 37 Code of Federa enefits under 35 U.S.C certificate, or § 365(a) an the United States, weign application for pat	I the contents of the ferred to above to be material to the Regulations. § 119(a)-(d) or § of any PCT Internation is listed belowent or inventor's of the ferred to a second to the content of the second to a second to the content of the second to the content of the second to the content of	the above-identifies the patentability of any ational application w, and have also tertificate, or PC					
	Application No.	Country	Day/Month/Year	Priori Claim	•					
_				D Yes	□No					
				Yes	□ No					
_		·		Yes	□No					
				□Ves	□ No					

Page 1

NEIFELD REF: OSEMDB15UPCTUS

We (I) hereby claim the benefit under Title 35, United States Code, § 119 (c) of any United States provisional application(s) listed below.

	-
60/520,322	November 17, 2003
60/527,306	December 8, 2003

We (I) hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, which is listed below, and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application.

Application Serial No.	Filing Date	Status (pending, patented, abandoned)

We (I) hereby grant power of attorney to the attorneys associated with Neifeld IP Law, PC customer number 31518 as our (my) attorneys, with full powers of substitution and revocation, to prosecute this application and to transact all business in the Patent Office connected therewith; and we (I) hereby request that all correspondence regarding this application be sent to the firm of NEIFELD IP LAW, P.C., whose Post Office Address is: 4813-B Eisenhower Avenue, Alexandria, Virginia 22304. We (I) authorize NEIFELD IP LAW, PC to fill in a "NEIFELD REF:" identifier on the pages of this declaration after we (I) sign.

We (I) declare that all statements made herein of our (my) own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful statements may jeopardize the validity of the application or any patent issuing thereon.

NEIFELD REF: OSE	EMDB15UPCTUS		
Walter David BRADDO	OCK IV	MARIEZ DADS	3/16/2006
NAME OF FIRST (SO	OLE) INVENTOR	Signature	Date
Residence Address:	1128 First Street NE, I	Rochester, MN 55901 USA	
Post Office Address:	Same as above		
Citizenship:	US		
NAME OF SECOND	INVENTOR	Signature	Date
Residence Address:			
Post Office Address:			
Citizenship:	<u></u>		
NAME OF THIRD IN	VENTOR	Signature	Date
Residence Address:			
Post Office Address:		<u> </u>	
Citizenship:			
NAME OF FOURTH	INVENTOR	Signature	Date
Residence Address:			
Post Office Address:			
Citizenship:		····	

Page 3

2:1004 5/16/06 3-0-3 NEIFELD REF.: OSEMDB15UPCTUS

1AP20R3567011779 10 1177 2006

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF: Braddock

USPTO CONFIRMATION CODE: Unknown

US OR 371 APPLICATION NO: Filed Herewith

US OR 371(C)(4) FILING DATE: Filed Herewith

GROUP ART UNIT: Unknown

TITLE: Nitride Metal Oxide Semiconductor Integrated Transistor Devices

37 CFR 1.33 REQUEST TO USE CUSTOMER NUMBER 31518 FOR CORRESPONDENCE AND ATTORNEYS OF RECORD

Please use the address associated with the customer number 31518 for the correspondence address.

Please recognize the attorneys associated with the customer number 31518 as attorneys of record.

NEIFELD IP LAW, PC CUSTOMER NUMBER: 31518

NEIFELD IP LAW, PC CURRENT POSTAL ADDRESS:

Neifeld IP Law, PC

4813-B Eisenhower Avenue

Alexandria, Virginia 22304

Date:

Richard Neifeld

Registration No. 35, 299

Attorney of Record